## BC556B, BC557, A, B, C, BC558B, C

## Amplifier Transistors <br> PNP Silicon

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Collector-Emitter Voltage  <br>  BC556 <br>  BC557 <br>  BC558 | $V_{\text {CEO }}$ | $\begin{aligned} & -65 \\ & -45 \\ & -30 \end{aligned}$ | Vdc |
| Collector-Base Voltage  <br>  BC556 <br>  BC557 <br>  BC558 | $\mathrm{V}_{\mathrm{CBO}}$ | $\begin{aligned} & -80 \\ & -50 \\ & -30 \end{aligned}$ | Vdc |
| Emitter-Base Voltage | VEBO | -5.0 | Vdc |
| Collector Current - Continuous <br> - Peak | $\begin{aligned} & \text { IC } \\ & \text { ICM } \end{aligned}$ | $\begin{aligned} & -100 \\ & -200 \end{aligned}$ | mAdc |
| Base Current - Peak | IBM | -200 | mAdc |
| Total Device Dissipation <br> @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ <br> Derate above $25^{\circ} \mathrm{C}$ | PD | $\begin{gathered} 625 \\ 5.0 \end{gathered}$ | $\underset{\mathrm{mW} /{ }^{\circ} \mathrm{C}}{\mathrm{~mW}}$ |
| Total Device Dissipation @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ | PD | $\begin{aligned} & 1.5 \\ & 12 \end{aligned}$ | Watts <br> $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| Operating and Storage Junction Temperature Range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | $\begin{gathered} -55 \text { to } \\ +150 \end{gathered}$ | ${ }^{\circ} \mathrm{C}$ |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :---: | :---: | :---: | :---: |
| Thermal Resistance, <br> Junction to Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 200 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, <br> Junction to Case | $\mathrm{R}_{\theta \mathrm{JC}}$ | 83.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

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ORDERING INFORMATION

| Device | Package | Shipping |
| :---: | :---: | :---: |
| BC556B | TO-92 | 5000 Units/Box |
| BC556BRL1 | TO-92 | 2000/Tape \& Reel |
| BC556BZL1 | TO-92 | 2000/Ammo Pack |
| BC557 | TO-92 | 5000 Units/Box |
| BC557ZL1 | TO-92 | 2000/Ammo Pack |
| BC557A | TO-92 | 5000 Units/Box |
| BC557AZL1 | TO-92 | 2000/Ammo Pack |
| BC557B | TO-92 | 5000 Units/Box |
| BC557BRL1 | TO-92 | 2000/Tape \& Reel |
| BC557BZL1 | TO-92 | 2000/Ammo Pack |
| BC557C | TO-92 | 5000 Units/Box |
| BC557CZL1 | TO-92 | 2000/Ammo Pack |
| BC558B | TO-92 | 5000 Units/Box |
| BC558BRL | TO-92 | 2000/Tape \& Reel |
| BC558BRL1 | TO-92 | 2000/Tape \& Reel |
| BC558BZL1 | TO-92 | 2000/Ammo Pack |
| BC558C | TO-92 | 5000 Units/Box |
| BC558CRL1 | TO-92 | 2000/Tape \& Reel |
| BC558ZL1 | TO-92 | 2000/Ammo Pack |
| BC558CZL1 | TO-92 | 2000/Ammo Pack |

## BC556B, BC557, A, B, C, BC558B, C

ELECTRICAL CHARACTERISTICS $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic |  | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |  |
| Collector-Emitter Breakdown Voltage $\left(\mathrm{IC}=-2.0 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right)$ | $\begin{aligned} & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \end{aligned}$ | $\mathrm{V}_{\text {(BR) }}$ CEO | $\begin{aligned} & -65 \\ & -45 \\ & -30 \end{aligned}$ | - | - | V |
| Collector-Base Breakdown Voltage ( $\mathrm{I} \mathrm{C}=-100 \mu \mathrm{Adc}$ ) | $\begin{aligned} & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \end{aligned}$ | $\mathrm{V}_{(\mathrm{BR}) \mathrm{CBO}}$ | $\begin{aligned} & -80 \\ & -50 \\ & -30 \end{aligned}$ | - | - | V |
| Emitter-Base Breakdown Voltage $(\mathrm{I} E=-100 \mu \mathrm{Adc}, \mathrm{I} \mathrm{C}=0)$ | BC556 BC557 BC558 | $\mathrm{V}_{(\mathrm{BR}) \mathrm{EBO}}$ | $\begin{aligned} & -5.0 \\ & -5.0 \\ & -5.0 \end{aligned}$ | - | - | V |
| Collector-Emitter Leakage Current $\begin{aligned} & \left(\mathrm{V}_{\text {CES }}=-40 \mathrm{~V}\right) \\ & \left(\mathrm{V}_{\text {CES }}=-20 \mathrm{~V}\right) \end{aligned}$ $\left(\mathrm{V}_{\mathrm{CES}}=-20 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=125^{\circ} \mathrm{C}\right)$ | $\begin{aligned} & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \\ & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \end{aligned}$ | ICES | - | $\begin{gathered} -2.0 \\ -2.0 \\ -2.0 \\ - \\ - \end{gathered}$ | $\begin{aligned} & -100 \\ & -100 \\ & -100 \\ & -4.0 \\ & -4.0 \\ & -4.0 \end{aligned}$ | nA <br> $\mu \mathrm{A}$ |

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ELECTRICAL CHARACTERISTICS $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |

ON CHARACTERISTICS

| DC Current Gain $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=-10 \mu \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{~V}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=-2.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{~V}\right) \end{aligned}$ $\left(\mathrm{I}_{\mathrm{C}}=-100 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{~V}\right)$ | A Series Device B Series Devices C Series Devices BC557 <br> A Series Device B Series Devices C Series Devices A Series Device B Series Devices C Series Devices | hFE | $\begin{gathered} - \\ - \\ 120 \\ 120 \\ 180 \\ 420 \\ - \\ - \end{gathered}$ | $\begin{gathered} 90 \\ 150 \\ 270 \\ - \\ 170 \\ 290 \\ 500 \\ 120 \\ 180 \\ 300 \end{gathered}$ |  | - |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Saturation Voltage <br> ( $\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-0.5 \mathrm{mAdc}$ ) <br> ( $\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=$ see Note 1) <br> ( $\mathrm{I} \mathrm{C}=-100 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-5.0 \mathrm{mAdc}$ ) |  | $\mathrm{V}_{\text {CE }}$ (sat) |  | $\begin{gathered} -0.075 \\ -0.3 \\ -0.25 \end{gathered}$ | $\begin{array}{r} -0.3 \\ -0.6 \\ -0.65 \end{array}$ | V |
| Base-Emitter Saturation Voltage $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-0.5 \mathrm{mAdc}\right) \\ & \left(\mathrm{I} \mathrm{C}=-100 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-5.0 \mathrm{mAdc}\right) \end{aligned}$ |  | $\mathrm{V}_{\text {BE }}$ (sat) |  | $\begin{aligned} & -0.7 \\ & -1.0 \end{aligned}$ | - | V |
| Base-Emitter On Voltage $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=-2.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{IC}=-10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{Vdc}\right) \end{aligned}$ |  | $V_{B E}$ (on) | $-0.55$ | $\begin{gathered} -0.62 \\ -0.7 \end{gathered}$ | $\begin{aligned} & -0.7 \\ & -0.82 \end{aligned}$ | V |

## SMALL-SIGNAL CHARACTERISTICS

| $\begin{aligned} & \text { Current-Gain - Bandwidth Product } \\ & \quad\left(\mathrm{IC}_{\mathrm{C}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{~V}, \mathrm{f}=100 \mathrm{MHz}\right) \end{aligned}$ | $\begin{aligned} & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \end{aligned}$ | ${ }^{\text {T }}$ | - | $\begin{aligned} & 280 \\ & 320 \\ & 360 \end{aligned}$ | - | MHz |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=-10 \mathrm{~V}, \mathrm{I} \mathrm{C}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ |  | Cob | - | 3.0 | 6.0 | pF |
| $\begin{aligned} & \text { Noise Figure } \\ & \quad\left(\mathrm{I} \mathrm{C}=-0.2 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-5.0 \mathrm{~V},\right. \\ & \mathrm{RS}_{\mathrm{S}}=2.0 \mathrm{k} \Omega, \mathrm{f}=1.0 \mathrm{kHz}, \Delta \mathrm{f}=200 \mathrm{~Hz} \text { ) } \end{aligned}$ | $\begin{aligned} & \text { BC556 } \\ & \text { BC557 } \\ & \text { BC558 } \end{aligned}$ | NF | - | $\begin{aligned} & 2.0 \\ & 2.0 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & 10 \\ & 10 \\ & 10 \end{aligned}$ | dB |
| Small-Signal Current Gain $\left(\mathrm{IC}=-2.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | BC557 <br> A Series Device B Series Devices C Series Devices | $\mathrm{hfe}^{\text {f }}$ | $\begin{aligned} & 125 \\ & 125 \\ & 240 \\ & 450 \end{aligned}$ | - | $\begin{aligned} & 900 \\ & 260 \\ & 500 \\ & 900 \end{aligned}$ | - |

Note 1: $\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}$ on the constant base current characteristics, which yields the point $\mathrm{I}_{\mathrm{C}}=-11 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=-1.0 \mathrm{~V}$.

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Figure 1. Normalized DC Current Gain


Figure 3. Collector Saturation Region


Figure 5. Capacitances


Figure 2. "Saturation" and "On" Voltages


Figure 4. Base-Emitter Temperature Coefficient


Figure 6. Current-Gain - Bandwidth Product

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BC556


Figure 7. DC Current Gain


Figure 9. Collector Saturation Region


Figure 11. Capacitance


Figure 8. "On" Voltage


Figure 10. Base-Emitter Temperature Coefficient


Figure 12. Current-Gain - Bandwidth Product

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Figure 13. Thermal Response


Figure 14. Active Region - Safe Operating Area

The safe operating area curves indicate $\mathrm{I}_{\mathrm{C}}-\mathrm{V}_{\mathrm{CE}}$ limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $\mathrm{T}_{\mathrm{J}(\mathrm{pk})}=150^{\circ} \mathrm{C}$; $\mathrm{T}_{\mathrm{C}}$ or $\mathrm{T}_{\mathrm{A}}$ is variable depending upon conditions. Pulse curves are valid for duty cycles to $10 \%$ provided $\mathrm{T}_{\mathrm{J}(\mathrm{pk})} \leq 150^{\circ} \mathrm{C} . \mathrm{T}_{\mathrm{J}(\mathrm{pk})}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

## BC556B, BC557, A, B, C, BC558B, C

## PACKAGE DIMENSIONS

TO-92
(TO-226)
CASE 29-11
ISSUE AL


NOTES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|  | INCHES |  | MILLIMETERS |  |
| :---: | ---: | ---: | ---: | ---: |
| DIM | IIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.115 | --- | 2.93 | --- |
| V | 0.135 | --- | 3.43 | --- |

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

## BC556B, BC557, A, B, C, BC558B, C

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